

# Publisher Correction: Single-crystalline metal-oxide dielectrics for top-gate 2D transistors

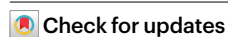
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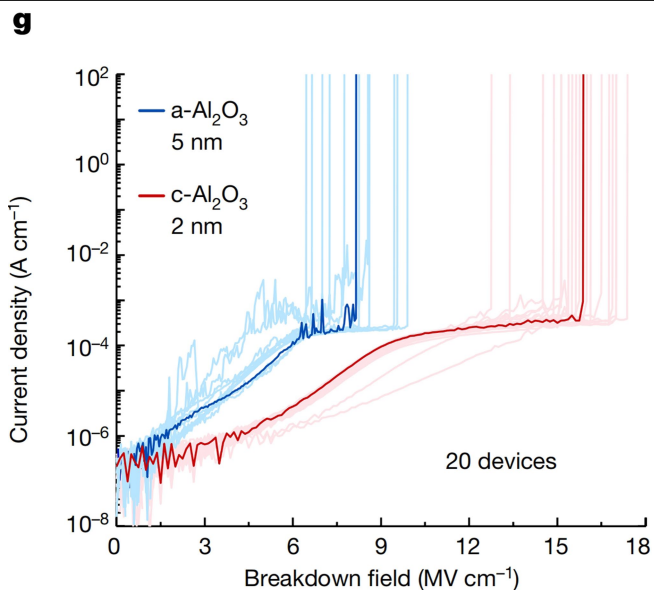
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In the version of the article initially published, in the key to Fig. 1g, the label now reading “c-Al<sub>2</sub>O<sub>3</sub> 2 nm” originally read “a-Al<sub>2</sub>O<sub>3</sub> 2 nm” and has now been amended in the HTML and PDF versions of the article.



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**Fig. 1 | Correct figure.**